



PTO/SB/08 A & B (modified)

Substitute for form 1449 A & B/PTO

**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**

(use as many sheets as necessary)

Complete if Known

Application Number	10/074,023
Confirmation Number	5637
Filing Date	February 14, 2002
First Named Inventor	Fabrice DEVAUX
Art Unit	2874
Examiner Name	Unknown
Attorney Docket Number	Q68526

Sheet 1 of 1

U.S. PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Document Number		Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document
		Number	Kind Code ² (if known)		
		US			
		US			
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		US			

FOREIGN PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Foreign Patent Document			Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Translation ⁴
		Country Code ³	Number ⁴	Kind Code ⁵ (if known)			
JH		FR	2 663 161	A1	12-13-1991	Thomson CSF	No
JH		FR	2 768 524	A1	3-19-1999	France Telecom	No
JH		JP	58 151087	A	9-8-1983	Nippon Telegr & Teleph Corp	W/English Abstract

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city, and/or country where published.	Translation ⁶
JH		YU-HENG JAN et al.: "Vertical Monolithic Integration of a GAAS/ALGAAS V-Channeled Substrate Inner Stripe Laser Diode and A Heterojunction Bipolar Transistor" Applied Physics Letters, American Institute of Physics. New York, US, vol. 57, no. 26, December 24, 1990, pages 2750 - 2752	Yes
JH		YOSHITAKA OKADA ET AL: "Optical Intensity Modulator for Integrated Optics by use of a Heterojunction Bipolar Transistor Waveguide Structure" Applied Physics Letters, American Institute of Physics. New York, US, vol. 55, no. 25, December 18, 1989, pages 2591-2593, XP000126806.	Yes

Examiner Signature

Date Considered

1/30/04

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Applicant's unique citation designation number (optional). ² See Kinds Codes of USPTO Patent Documents at www.uspto.gov, MPEP 901.04 or in the comment box of this document. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST. 3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶ Applicant is to indicate here if English language Translation is attached.